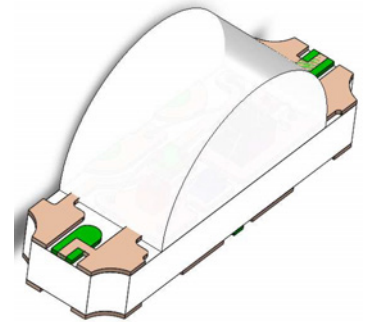


1.产品概述 Product overview:

- 工作电压：5V@12mA(OUT GRB) ;
Forward voltage: 5V@12mA (OUT GRB) ;
- 发光角度：160°;
Luminescent angle: 160 ° ;
- 胶体颜色：半透明;
Lens color: translucent ;
- 内置复位电路，上电不亮灯;
Built-in reset circuit, power does not light ;
- 灰度调节：256级;
Grayscale adjustment： 256 levels ;
- 单线归零码传输协议，可无限级联;
Single-line zero code transmission protocol, can be infinite cascade ;
- 数据传输频率可达800Kbps， 当刷新速率30帧/秒时，级联数不小于1024点;
The data transmission frequency can reach 800Kbps, and when the refresh rate is 30 frames per second, the number of cascades is not less than 1024 points ;
- 湿敏等级：4 ;
MSL： 4 ;
- 静电ESD： 5KV;
ESD level: 5KV;
- 符合RoHS REACH;
RoHS and REACH-compliant;



2.主要应用 Main applications:

- 消费电子产品
Consumer electronics

3. 产品命名一般说明 General instructions for product naming:

YS-IC3210RGB12-S-P

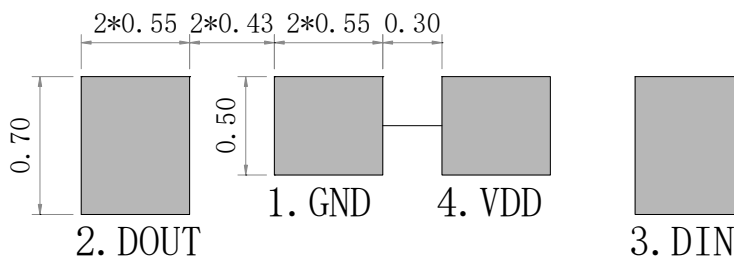
① ② ③ ④ ⑤

①	②	③	④	⑤
系列 Series	封装外形 Package outline	颜色代码与电流 Color codes and current	Lens形状 Lens shape	内部编码 Internal code
默认为GRB晶片与 IC集成在一起 Default to GRB chip integrated with IC	3.2x1.0x1.48毫米 PCB支架封装 3.2x1.0x1.48mm PCB bracket packaging	R/G/B: 12mA电流版本 R/G/B: 12mA current version	S: 表示侧光 S: Representing sideview	P: 内部编码 P: Internal code

6.PCB建议焊盘尺寸 PCB recommended pad size:

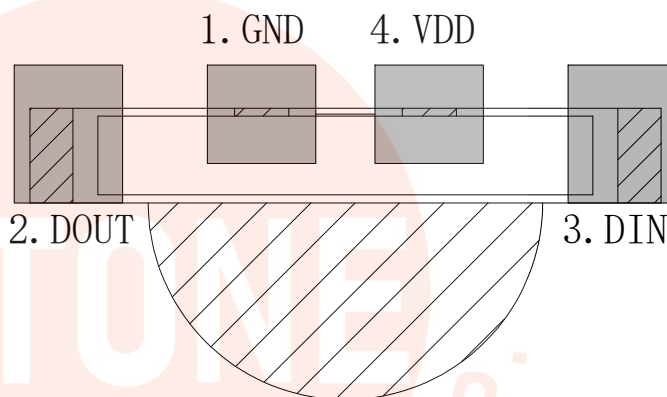
TOP VIEW

侧面贴装建议焊盘尺寸
Suggested solder pad
size for side mounting



侧面贴装示意图

Side mounting diagram



7.IC极限参数 IC limit parameter : (Ta=25°C)

参数 Parameter	符号 Symbol	范围 Range	单位 Unit
逻辑电源电压 Working voltage	V _{in}	3.7~5.5	V
工作温度 Operation temperature	T _{opt}	-40~+85	°C
储存温度 Storage temperature	T _{stg}	-40~+85	°C
ESD耐压 (人体模式) ESD withstand voltage (human mode)	V _{ESD}	5K	V

8. GRB LED 光电参数 Optoelectronic parameters:

颜色 Colour	YS-IC3210RGB12-S-P 12mA	
	波长 (nm) Wavelength (nm)	亮度 (mcd) Brightness (mcd)
绿色 (GREEN)	520-525	450-815
红色 (RED)	620-625	140-280
蓝色 (BLUE)	465-470	120-240

9. IC电气参数 IC electrical parameters: (TA=25°C)

参数 Parameter	符号 Symbol	最小 Minimum	典型 Typical	最大 Maximum	单位 Unit	测试条件 Test conditions
工作电压 Chip input voltage	VDD	3.7	5	5.5	V	---
信号输入翻转阈值 Signal input flip threshold	VIH	0.7VDD	---	---	V	+VDD=5.0V
	VIL	---	---	0.3VDD	V	
G/R/B输出驱动电流 G/R/B output drive current	I _{DOUT}	9.6	12	14.5	mA	V _{DS} =1V
PWM频率 PWM frequency	F _{PWM}	---	4	---	KHz	---
静态功耗 Static power consumption	I _{DD}	---	0.35	---	mA	---
数据传输速率 Transfer rate	F _{DIN}	---	800	---	Kbps	---

10. 建议数据传输时间 Suggested data transmission time:

时序表名称 Timeline Name	Min.	实际值 Actual value	Max.	单位 Unit
T 码元周期 Symbol period	1.2	---	---	us
T0H 0码, 高电平时间 0 code, high-level time	0.2	0.3	0.4	us
T0L 0码, 低电平时间 0 code, low-level time	0.6	--	--	us
T1H 1码, 高电平时间 1 code, high-level time	0.58	0.65	1.0	us
T1L 1码, 低电平时间 1 code, low-level time	0.2	--	--	us
Reset Reset码, 低电平时间 Reset code, low-level time	> 200	---	---	us

1. 协议采用单极性归零码, 每个码元必须有低电平, 本协议的每个码元起始为高电平, 高电平时间宽度决定“0”码或“1”码。

The protocol adopts unipolar zeroing code, and each symbol must have a low level. Each symbol in this protocol starts with a high level, and the duration of the high level determines the "0" or "1" code.

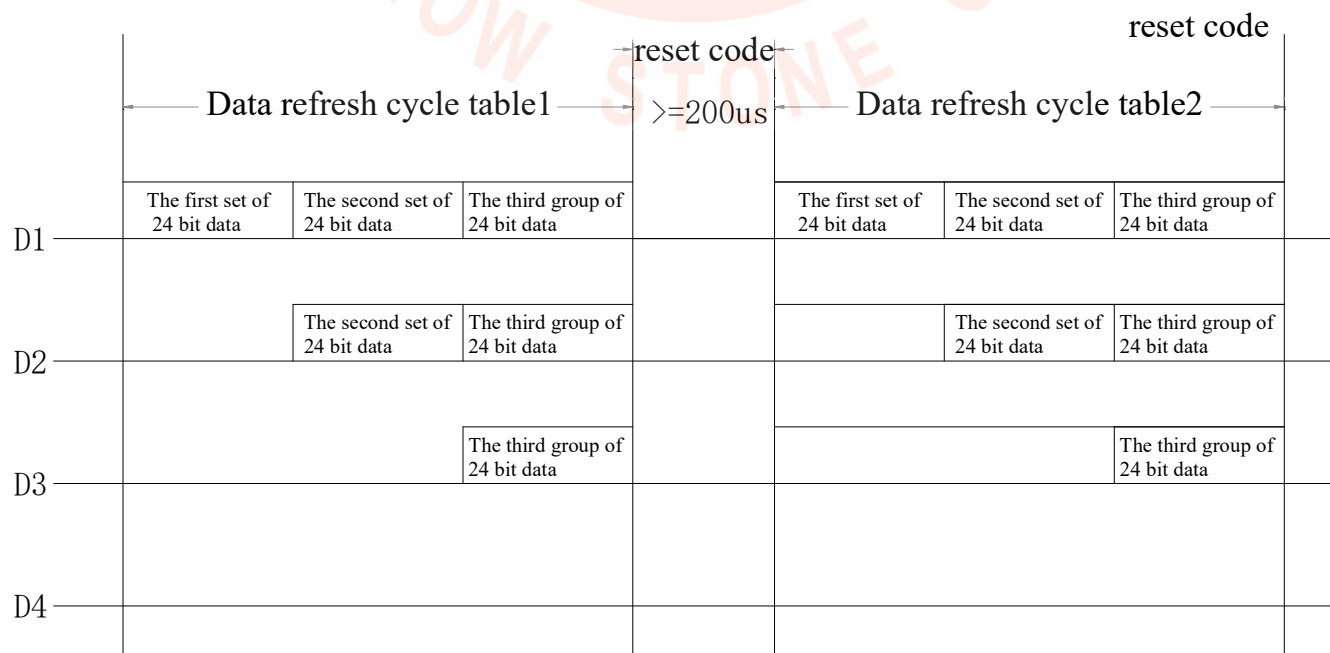
2. 书写程序时, 码元周期最低要求为1.2μs。

When writing a program, the minimum required code period is 1.2 μs.

3. “0”码、“1”码的高电平时间需按照上表的规定范围, “0”码、“1”码的低电平时间要求小于20μs。

The high-level time of "0" and "1" codes should be within the specified range in the table above, and the low-level time of "0" and "1" codes should be less than 20 μs

11. 数据传输方式 Data transmission method: (Ta=25°C)

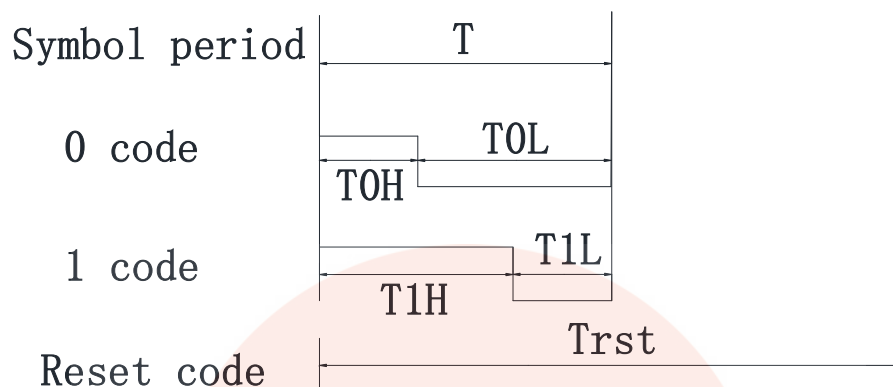


注Note: 其中D1为MCU端发送的数据, D2、D3、D4为级联电路自动整形转发的数据。

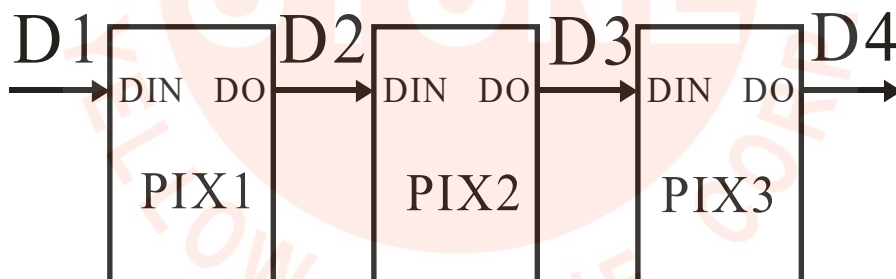
Among them, D1 is the data sent by the MCU end, and D2, D3, and D4 are the data automatically shaped and forwarded by the cascaded circuit.

12.时序波形图 Time series waveform diagram: ($T_a=25^{\circ}\text{C}$)

输入码型 Input code type:



连接方式 Connection method:



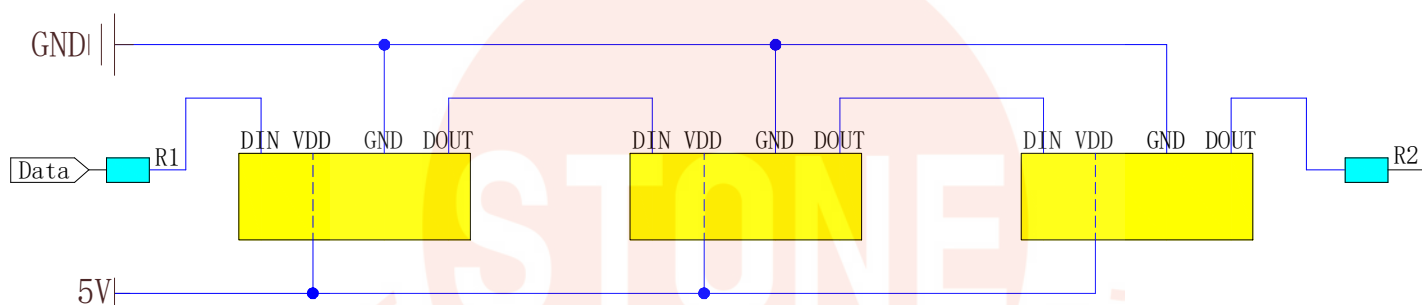
13. 24bit数据结构 24 bit data structure: (Ta=25°C)

G7	G6	G5	G4	G3	G2	G1	G0	R7	R6	R5	R4
R3	R2	R1	R0	B7	B6	B5	B4	B3	B2	B1	B0

注Note：高位先发，按照GRB的顺序发送数据(G7 → G6 →.....B0)

High bit first send, send data in GRB order (G7 → G6 →.... B0)

14. 典型应用电路 Typical application circuit:



在实际应用电路中，为防止产品在测试时带电插拔产生的瞬间高压损伤IC内部信号输入输出引脚，应在信号输入及输出端串接保护电阻。此外，为了使各IC芯片间更稳定工作，各灯珠间的退偶电容则必不可少；

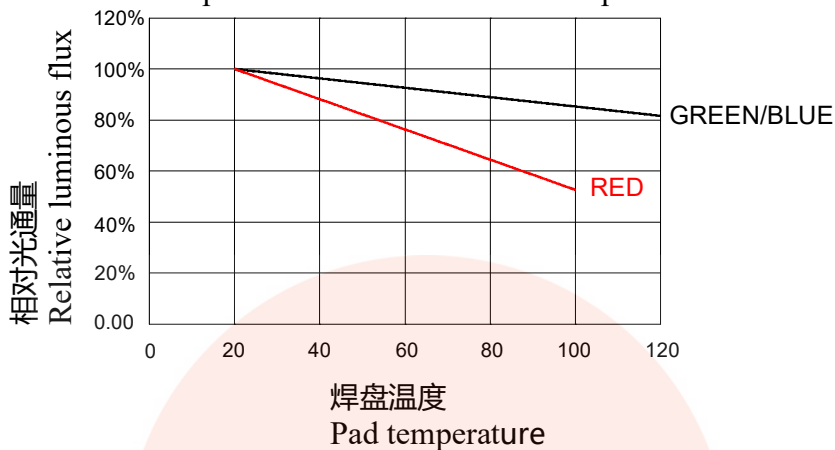
- 1.应用一：用于软灯灯或硬灯条的，灯珠间传输距离短的，建议在信号输入输出端各串接保护电阻，即R1=R2约500欧；
- 2.应用二：用于模组或3.一般异形产品，灯珠间传输距离长，因线材及传输距离不同，在信号两端串接的保护电阻会略有不同；以实际使用情况定；

In practical application circuits, to prevent instantaneous high voltage damage to the internal signal input and output pins of the IC caused by live plugging and unplugging during testing, protective resistors should be connected in series at the signal input and output terminals. In addition, in order to ensure more stable operation between IC chips, the decoupling capacitance between each LED is essential;

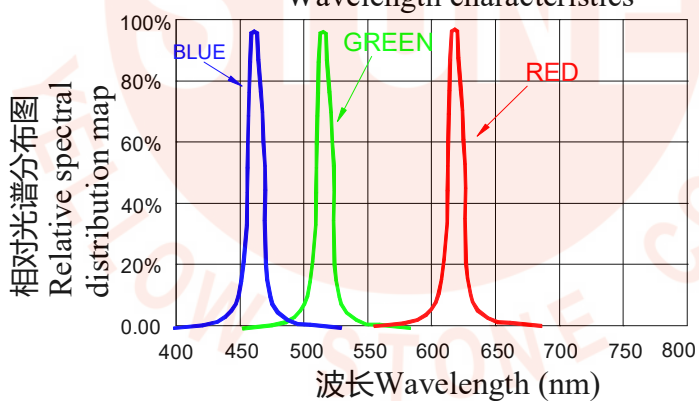
1. Application 1: For soft or hard light strips with short transmission distance between lamp beads, it is recommended to connect protective resistors in series at the signal input and output terminals, that is, R1=R2, about 500 ohms;
2. Application 2: Used for modules or 3. For general shaped products, the transmission distance between lamp beads is long. Due to different wire materials and transmission distances, the protective resistance connected in series at both ends of the signal will be slightly different; Based on actual usage;

15. 光电特性 Photoelectric characteristic:

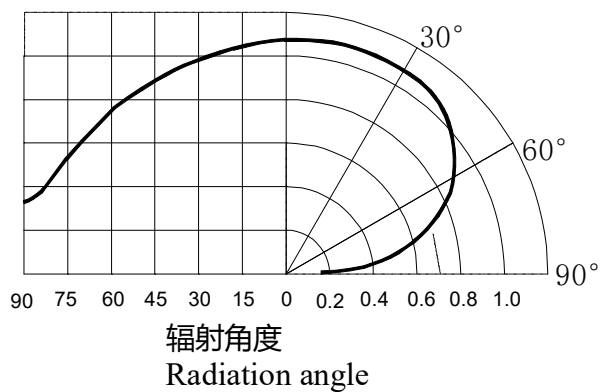
焊盘温度与光通量输出的相对关系
 The relative relationship between pad temperature and luminous flux output



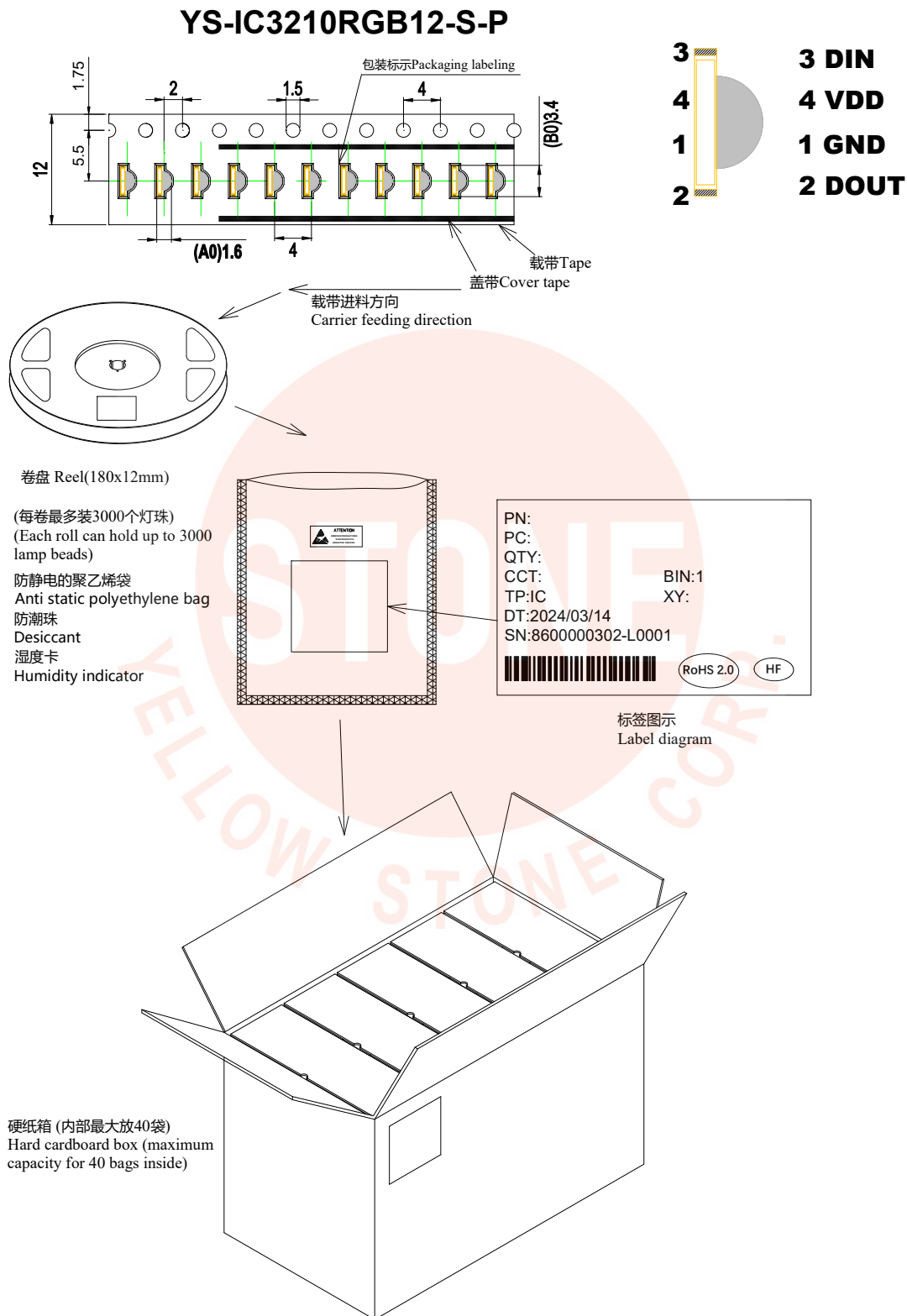
波长特性
 Wavelength characteristics



典型的辐射方向图 160°
 Typical radiation pattern 160°



16. 包装标准 Packaging standards:



表面贴装LED采用卷盘包装，LED在用普通或防静电袋包装后再装在纸箱中。纸箱用于保护运输途中LED不受机械冲击，纸箱不防水，因此请注意防潮防水。

Surface mounted LEDs are packaged in rolls, and the LEDs are packaged in regular or anti-static bags before being packed in cardboard boxes. The cardboard box is used to protect the LED from mechanical impact during transportation. The cardboard box is not waterproof, so please pay attention to moisture-proof and waterproof.

17. 可靠性测试 Reliability testing:

序号 Serial Number	实验项目 Pilot projects	实验条件 Experimental condition	参考标准 Reference standards	判断 Determine
1	冷热冲击 Thermal Shock	$100 \pm 5^{\circ}\text{C} \sim -40^{\circ}\text{C} \pm 5^{\circ}\text{C}$ 15min~15min 100cycles	MIL-STD-202G	0/22
2	高温储藏 High temperature storage	Ta= +100°C 1000hrs	JEITA ED-4701 200 201	0/22
3	低温储藏 Low temperature storage	Ta= -40°C 1000hrs	JEITA ED-4701 200 202	0/22
4	高温高湿储藏 High temperature and high humidity storage	Ta=60°C RH=90% 1000hrs	JEITA ED-4701 100 103	0/22
5	温度循环 Temperature cycling	-40°C~25°C~100°C~25°C 30min~5min~30min~5min 100 cycles	JEITA ED-4701 100 105	0/22
6	耐焊接热 Resistance to Soldering Heat	Tsld = 260°C, 10sec. 2 times	JEITA ED-4701 300 301	0/22
7	常温寿命测试 Normal temperature life test	25°C, IF: Typical current , 1000hrs	JESD22-A 108D	0/22

失效判定标准 Failure criteria:

项目 Project	符号 Symbol	测试条件 Test conditions	判断标准 Judgment criteria	
			最小值 Minimum value	最大值 Maximum value
发光强度 Intensity	IV	DC=5V,规格典型电流 DC=5V, typical current specification	初始数据X0.7 Initial data X0.7	---
耐焊接热 Resistance to Soldering Heat	---	DC=5V,规格典型电流 DC=5V, typical current specification	无死灯或明显损坏 No dead lights or obvious damage	